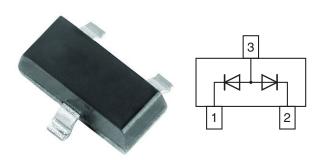


Vishay Semiconductors

Small Signal Switching Diode, Dual



FEATURES

- Silicon epitaxial planar diode
- · Fast switching dual diode with common anode
- AEC-Q101 qualified available (part number on request)
- Base P/N-G3 green, commercial grade
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





RoHS

HALOGEN FREE GREEN (5-2008)

DESIGN SUPPORT TOOLS click logo to get started



MECHANICAL DATA

Case: SOT-23

Weight: approx. 8.1 mg
Packaging codes / options:

18/10K per 13" reel (8 mm tape), 10K(/box 08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE					
PART	ORDERING CODE	CIRCUIT CONFIGURATION	TYPE MARKING	REMARKS	
BAW56-G	BAW56-G3-08 or BAW56-G3-18	Common anode	JDG	Tape and reel	

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Repetitive peak reverse voltage = working peak reverse voltage = DC blocking voltage		$V_R = V_{RRM}$	70	V	
Forward continuous current		I _F	250	mA	
	t _p = 1 μs	I _{FSM}	2	Α	
Non repetitive peak forward current	t _p = 1 ms	I _{FSM}	1	Α	
	t _p = 1 s	I _{FSM}	0.5	Α	
Power dissipation (1)		P _{tot}	350	mW	

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air		R _{thJA} (1)	430	K/W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-65 to +150	°C	
Operating temperature range		T _{op}	-55 to +150	°C	

Note

(1) Device on fiberglass substrate



Vishay Semiconductors

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I _F = 1 mA	V _F			0.715	V
Forward voltage	I _F = 10 mA	V _F			0.855	V
Forward voltage	$I_F = 50 \text{ mA}$	V _F			1	V
	I _F = 150 mA	V _F			1.25	V
	V _R = 70 V	I _R			2500	nA
Reverse current	$V_R = 70 \text{ V}, T_j = 150 ^{\circ}\text{C}$	I _R			100	μΑ
	V _R = 25 V, T _j = 150 °C	I _R			30	μA
Diode capacitance	$V_F = V_R = 0$, $f = 1$ MHz	C _D			2	pF
Reverse recovery time	I_F =10 mA to I_R =1 mA, V_R = 6 V, R_L = 100 Ω	t _{rr}			6	ns

TYPICAL CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified)

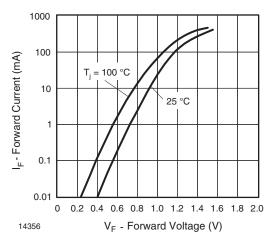


Fig. 1 - Forward Current vs. Forward Voltage

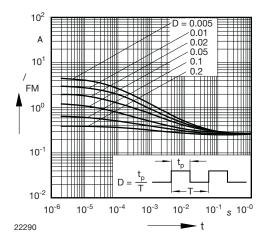
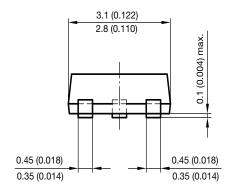


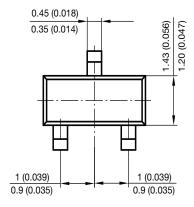
Fig. 2 - Peak Forward Current $f_{fm} = f(t_p)$



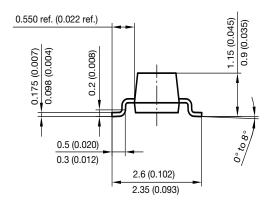
Vishay Semiconductors

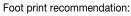
PACKAGE DIMENSIONS in millimeters (inches): SOT-23

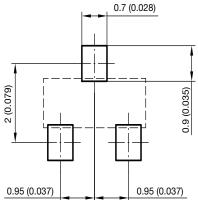




Document no.: 6.541-5014.01-4 Rev. 8 - Date: 23.Sept.2009 17418









Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by Vishay manufacturer:

Other Similar products are found below:

RD0306T-H BAV17-TR BAV19-TR 1N3611 NTE156A NTE525 NTE571 NTE574 NTE5804 NTE5806 NTE6244 1SS181-TP

1SS193,LF 1SS400CST2RA SDAA13 SHN2D02FUTW1T1G LS4151GS08 1N4449 1N456A 1N4934-E3/73 1N914B 1N914BTR

RFUH20TB3S BAS 28 E6327 BAV199-TP BAW56DWQ-7-F BAW75-TAP MM230L-CAA IDW40E65D1 JAN1N3600 LL4151-GS18

053684A SMMSD4148T3G 707803H NSVDAN222T1G SP000010217 CDSZC01100-HF BAV199E6433HTMA1 BAV70M3T5G

SMBT2001T1G NTE5801 NTE5800 NTE5808 NTE6240 NTE6248 BAS28-7 BAW56HDW-13 BAS28 TR VS-HFA04SD60STR-M3

NSVM1MA152WKT1G